

SF51G THRU SF58G



康比電子
HORNBY ELECTRONIC

SUPERFAST RECOVERY RECTIFIER

REVERSE VOLTAGE: 50 to 600 VOLTS

FORWARD CURRENT: 5.0 AMPERE

FEATURES

- High surge capability
- Low forward voltage, high current capability
- Hermetically sealed
- Superfast recovery times
- Low leakage.
- Glass Passivated Die Construction
- Suffix "H" indicates Halogen-free parts, ex. SF51GH

MECHANICAL DATA

Case : Molded plastic, DO-201AD

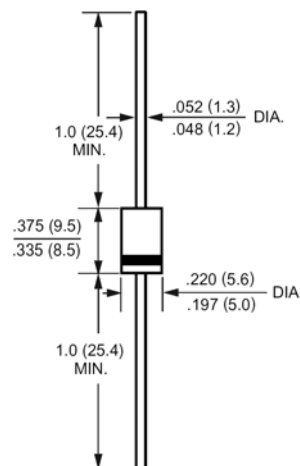
Epoxy : UL 94V-O rate flame retardant

Lead : Axial leads, solderable per MIL-STD-202,
method 208 guaranteed

Polarity : Color band denotes cathode end

Mounting position : Any

DO-201AD



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Parameter	Symbols	SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF58G	Units	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	Volts	
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	Volts	
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	Volts	
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at $T_A=55^\circ\text{C}$	$I_{(AV)}$	5.0							Amp	
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	150.0							Amp	
Maximum Forward Voltage at 5.0A DC and 25°C	V_F	0.95			1.3		1.7		Volts	
Maximum Reverse Current at $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_A=100^\circ\text{C}$	I_R	5.0				100				uAmp
Typical Junction Capacitance (Note 1)	C_J	120				60				pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	20.0							°C/W	
Maximum Reverse Recovery Time (Note 3)	T_{RR}	35							nS	
Operating and Storage Temperature Range	T_J, T_{stg}	-65 to +150							°C	

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- Thermal Resistance Junction to Ambient and from junction to lead at 0.375"(9.5mm) lead length P.C.B. Mounted.

3- Reverse Recovery Test Conditions: $I_F=5A$, $I_R=1A$, $I_{RR}=25A$.

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RATINGS AND CHARACTERISTIC CURVES

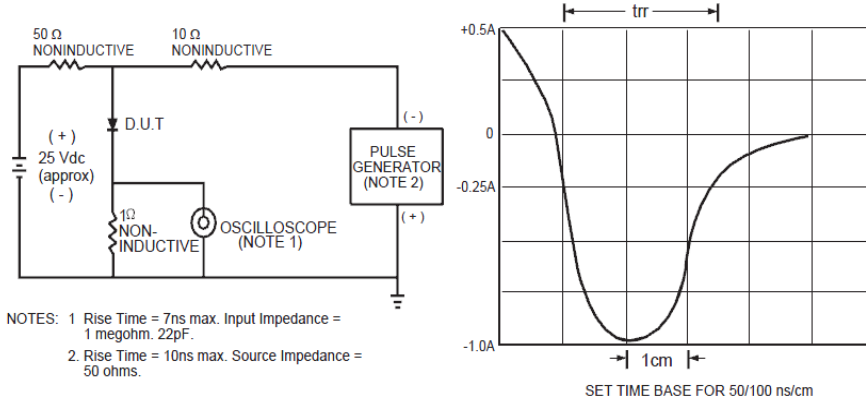


FIG.1 TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

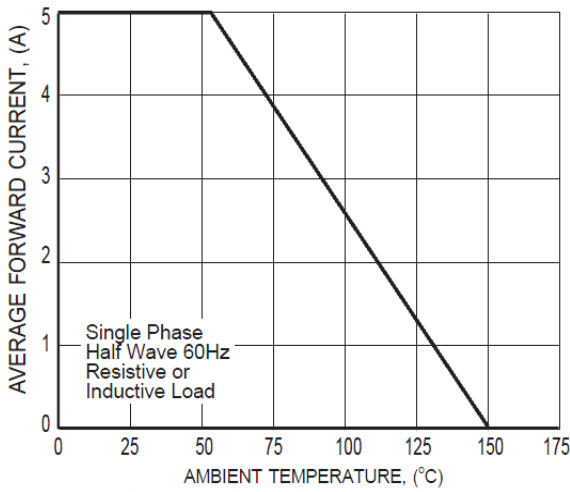


FIG.2 TYPICAL FORWARD CURRENT DERATING CURVE

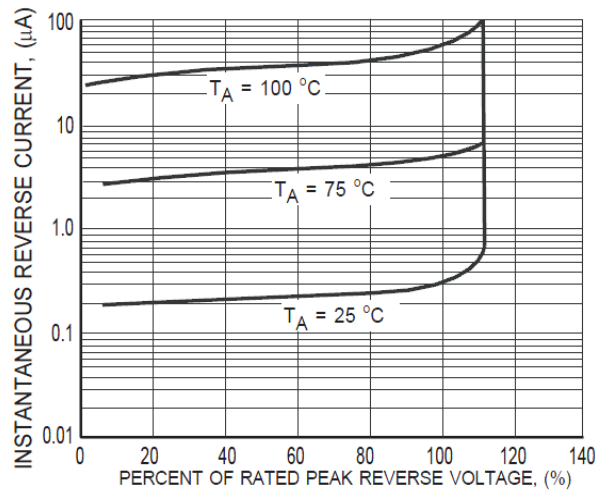


FIG.3 TYPICAL REVERSE CHARACTERISTICS

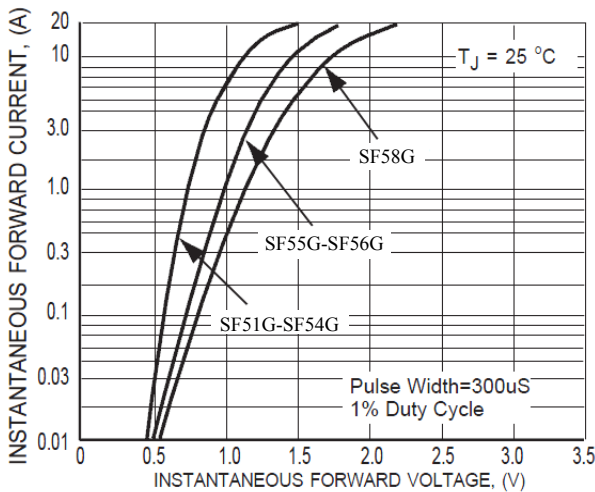


FIG.4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

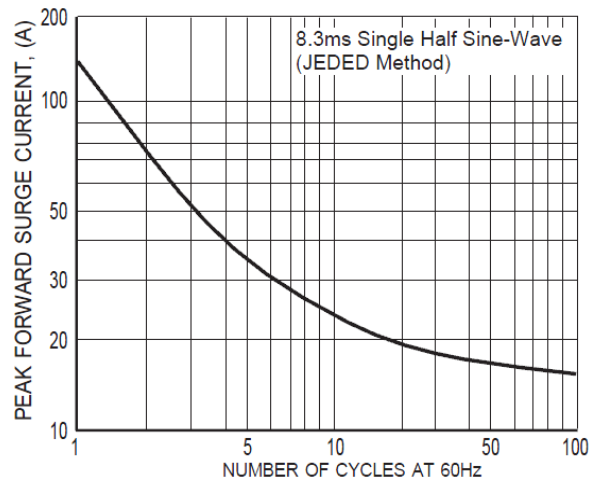


FIG.5 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT